NSN 5961-01-532-7908

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View Online at https://aerobasegroup.com/nsn/5961-01-532-7908 **Inclosure Material:** Metal **Overall Length:** Between 0.740 inches and 1.010 inches **Terminal Length:** Between 0.500 inches and 0.750 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-205 **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pnp **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.016 inches and 0.021 inches **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-emitter outside diameter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Used in high-speed power-switching applications **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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